NSN 5961-00-959-4565

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-959-4565 **Inclosure Material:** Metal **Overall Length:** 0.359 inches **Overall Diameter:** 0.424 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 off-state voltage, dc **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current minor **Power Rating Per Characteristic:** 50.0 milliwatts small-signal input power, common-collector outside diameter **Maximum Operating Tempurature Per Measurement Point:** 90.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: A110a0